NSN 5961-01-318-8817

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-318-8817 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 30.0 breakdown voltage, dc **Voltage Tolerance In Percent:** -10.0/+10.0 **Current Rating Per Characteristic:** 250.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 47.0 **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0